



ON Semiconductor®

<http://onsemi.com>

SFT1443

Power MOSFET

100V, 225mΩ, 9A, Single N-Channel

Features

- High Speed Switching
- Low Gate Charge
- Pb-free, Halogen-free and RoHS Compliance
- ESD Diode-Protected Gate

Specifications

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

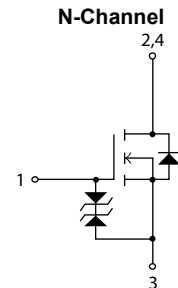
Parameter	Symbol	Value	Unit
Drain to Source Voltage	V_{DS}	100	V
Gate to Source Voltage	V_{GS}	± 20	V
Drain Current (DC)	I_D	9	A
Drain Current $PW \leq 10\mu\text{s}$, duty cycle $\leq 1\%$	I_{DP}	36	A
Power Dissipation	P_D	1.0	W
		19	W
		$T_c = 25^\circ\text{C}$	
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

Thermal Resistance Ratings

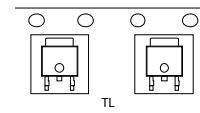
Parameter	Symbol	Value	Unit
Junction to Case Steady State	$R_{\theta JC}$	6.58	$^\circ\text{C/W}$
Junction to Ambient *1	$R_{\theta JA}$	125	

Note : *1 Insertion mounted

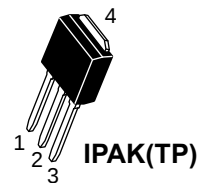
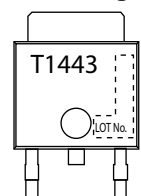
Electrical Connection



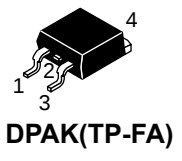
Packing Type: TL



Marking



IPAK(TP)



DPAK(TP-FA)

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ORDERING INFORMATION

See detailed ordering and shipping information on page 6 of this data sheet.

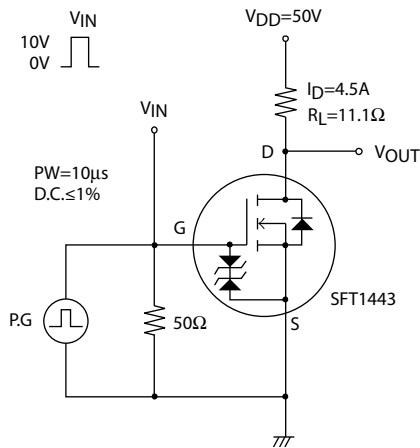
SFT1443

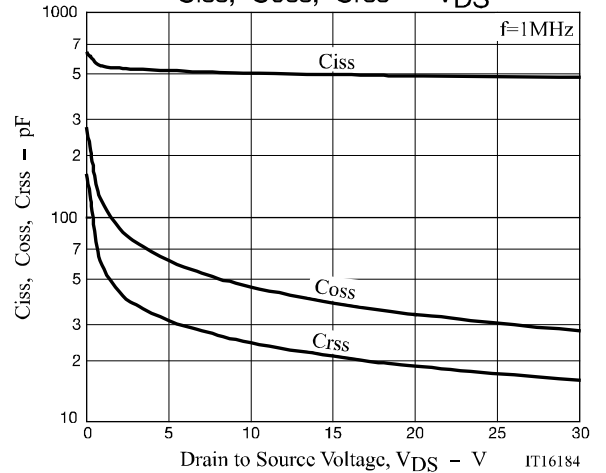
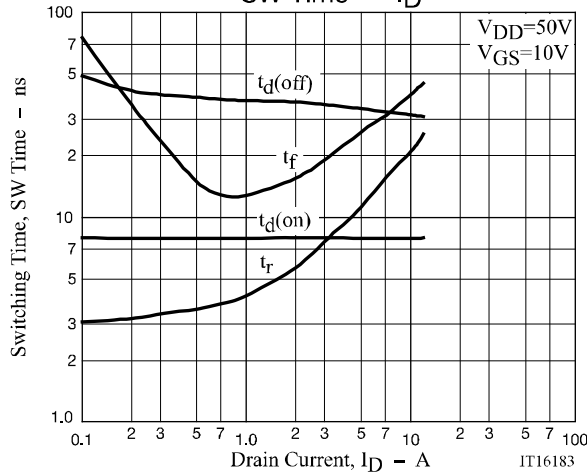
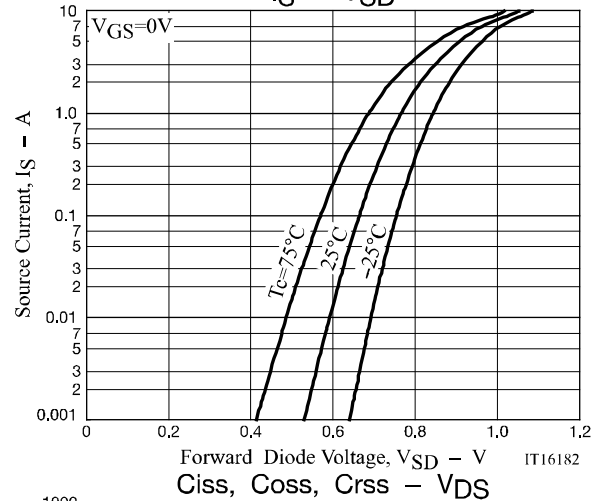
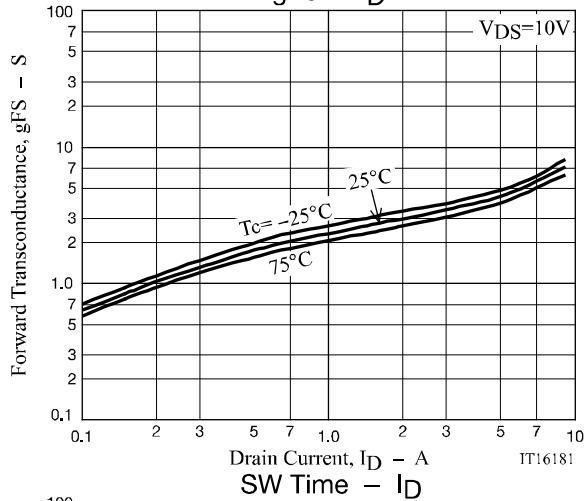
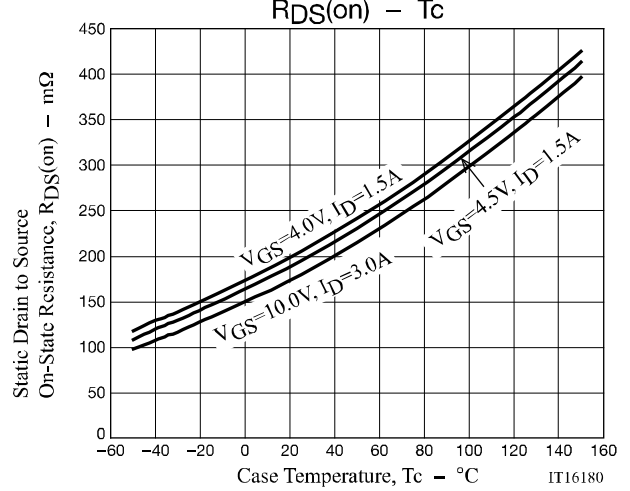
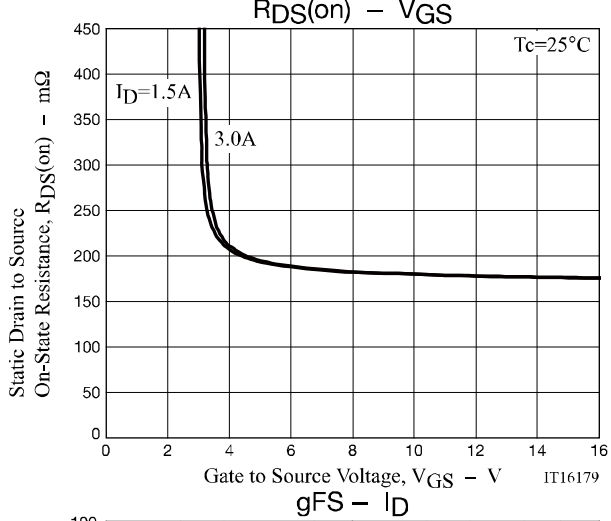
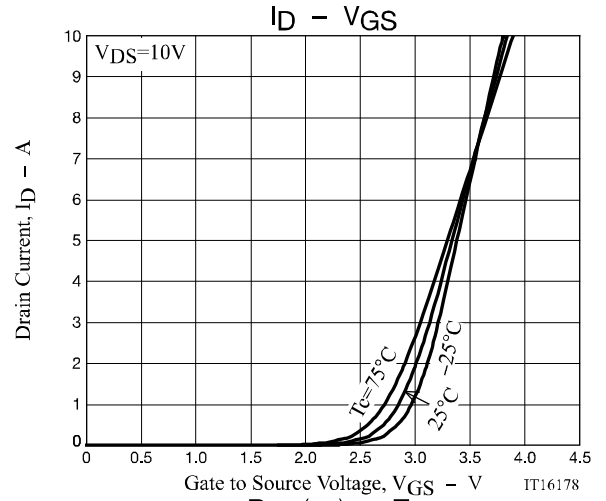
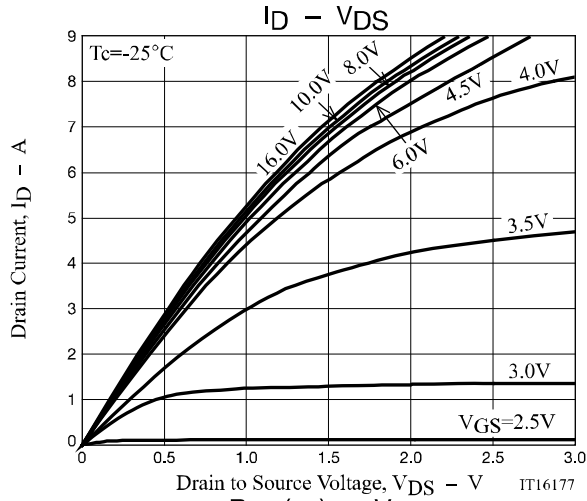
Electrical Characteristics at $T_a = 25^\circ\text{C}$

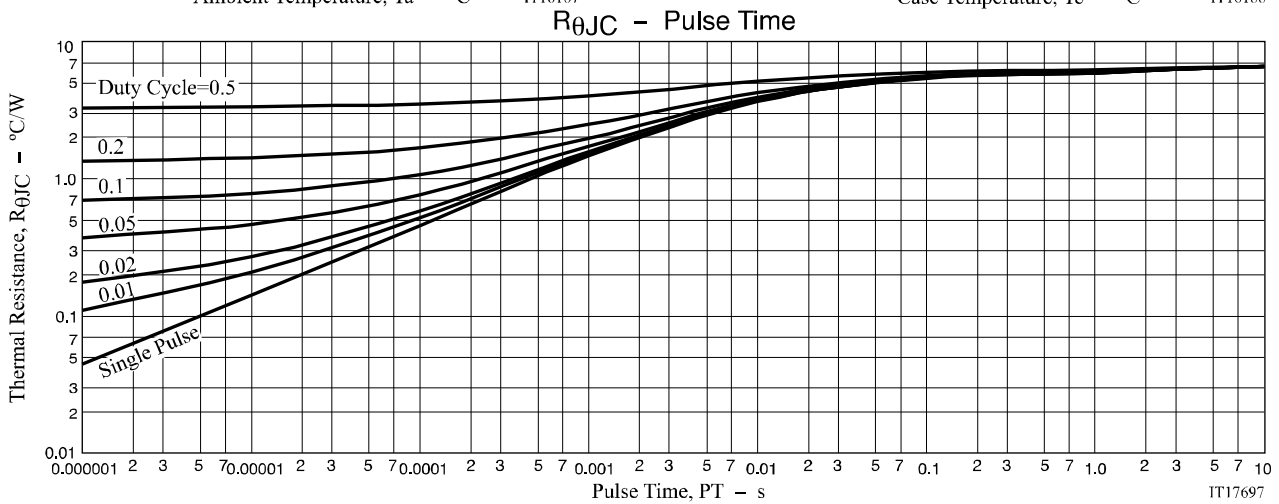
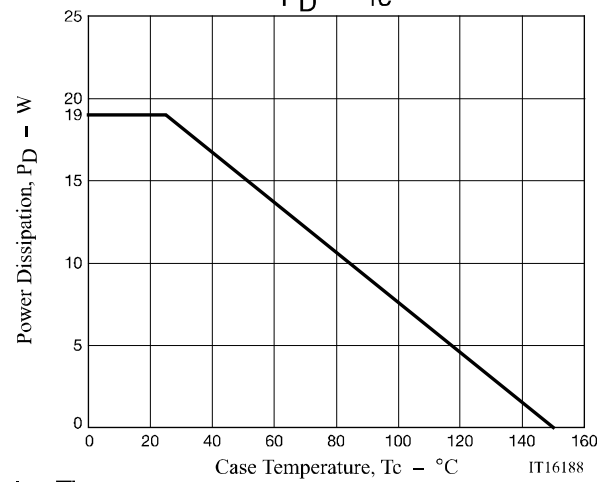
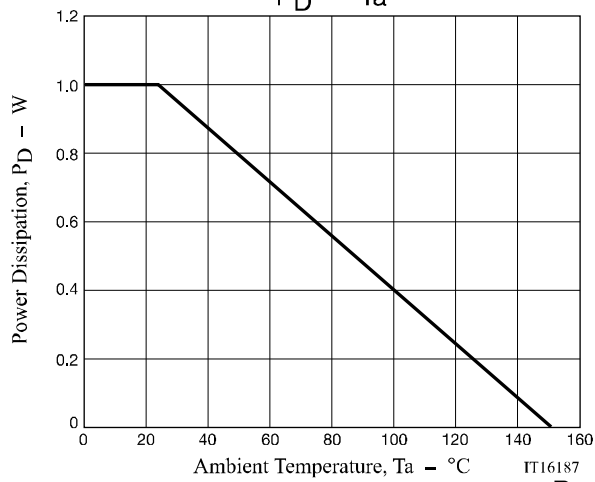
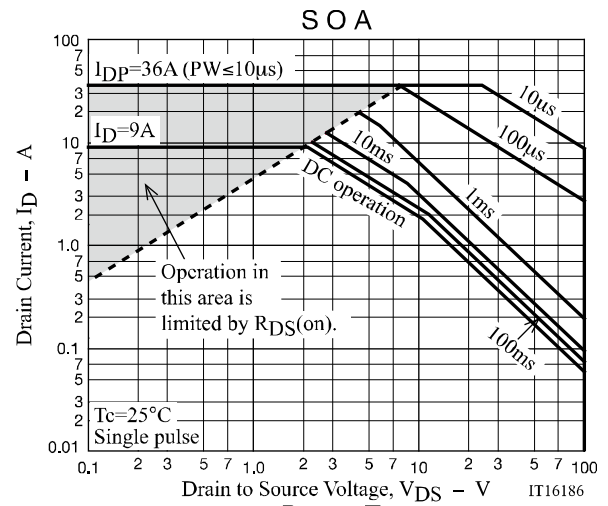
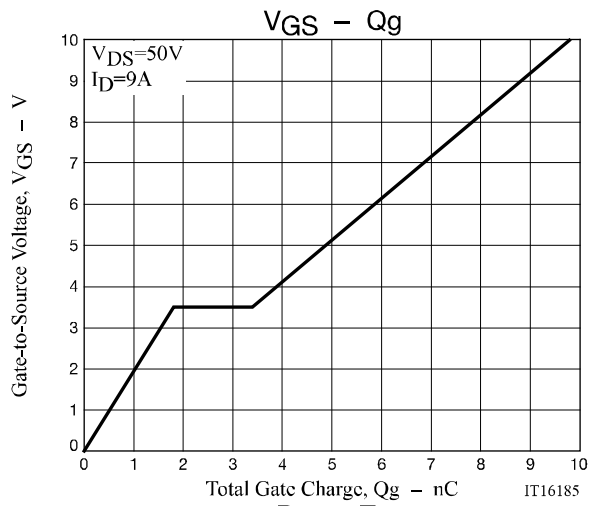
Parameter	Symbol	Conditions	Value			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=1\text{mA}$, $V_{GS}=0\text{V}$	100			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS}=100\text{V}$, $V_{GS}=0\text{V}$			1	μA
Gate to Source Leakage Current	I_{GSS}	$V_{GS}=\pm 16\text{V}$, $V_{DS}=0\text{V}$			± 10	μA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=10\text{V}$, $I_D=1\text{mA}$	1.5		2.6	V
Forward Transconductance	g_{FS}	$V_{DS}=10\text{V}$, $I_D=4.5\text{A}$		4		S
Static Drain to Source On-State Resistance	$R_{DS(on)1}$	$I_D=3\text{A}$, $V_{GS}=10\text{V}$		180	225	$\text{m}\Omega$
	$R_{DS(on)2}$	$I_D=1.5\text{A}$, $V_{GS}=4.5\text{V}$		195	275	$\text{m}\Omega$
	$R_{DS(on)3}$	$I_D=1.5\text{A}$, $V_{GS}=4\text{V}$		205	290	$\text{m}\Omega$
Input Capacitance	C_{iss}	$V_{DS}=20\text{V}$, $f=1\text{MHz}$		490		pF
Output Capacitance	C_{oss}			34		pF
Reverse Transfer Capacitance	C_{rss}			19		pF
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit.		8		ns
Rise Time	t_r			10		ns
Turn-OFF Delay Time	$t_{d(off)}$			34		ns
Fall Time	t_f			24		ns
Total Gate Charge	Q_g	$V_{DS}=50\text{V}$, $V_{GS}=10\text{V}$, $I_D=9\text{A}$		9.8		nC
Gate to Source Charge	Q_{gs}			1.8		nC
Gate to Drain "Miller" Charge	Q_{gd}			1.6		nC
Forward Diode Voltage	V_{SD}	$I_S=9\text{A}$, $V_{GS}=0\text{V}$		1.03	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Switching Time Test Circuit







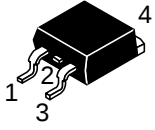
SFT1443

Package Dimensions

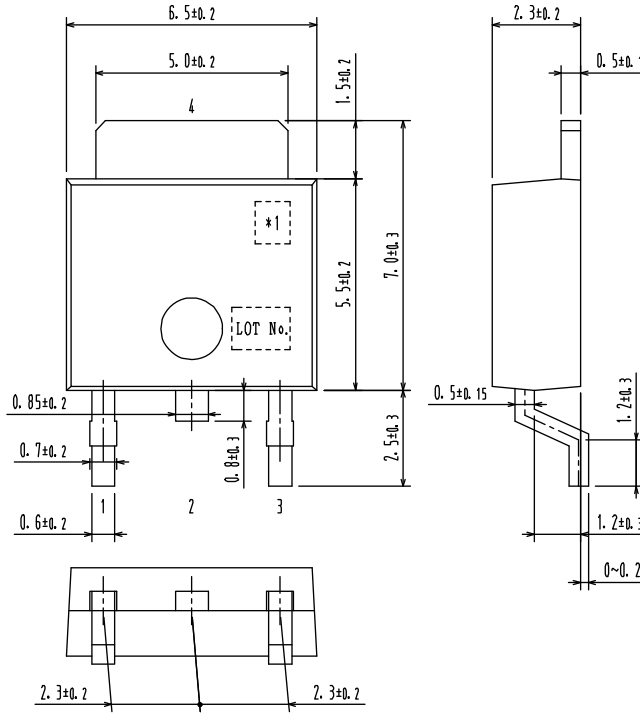
SFT1443-TL-H/ SFT1443-TL-W

DPAK/TP-FA

unit : mm



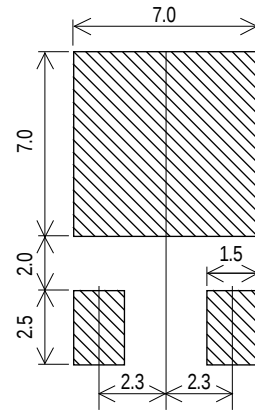
- 1:Gate
- 2:Drain
- 3:Source
- 4:Drain



Pin 2 is idle pin with electrical designation only carried.

*|:Lot indication

Recommended Soldering Footprint

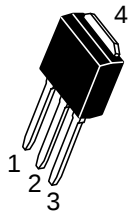


Package Dimensions

SFT1443-H/ SFT1443-W

IPAK/TP

Unit : mm

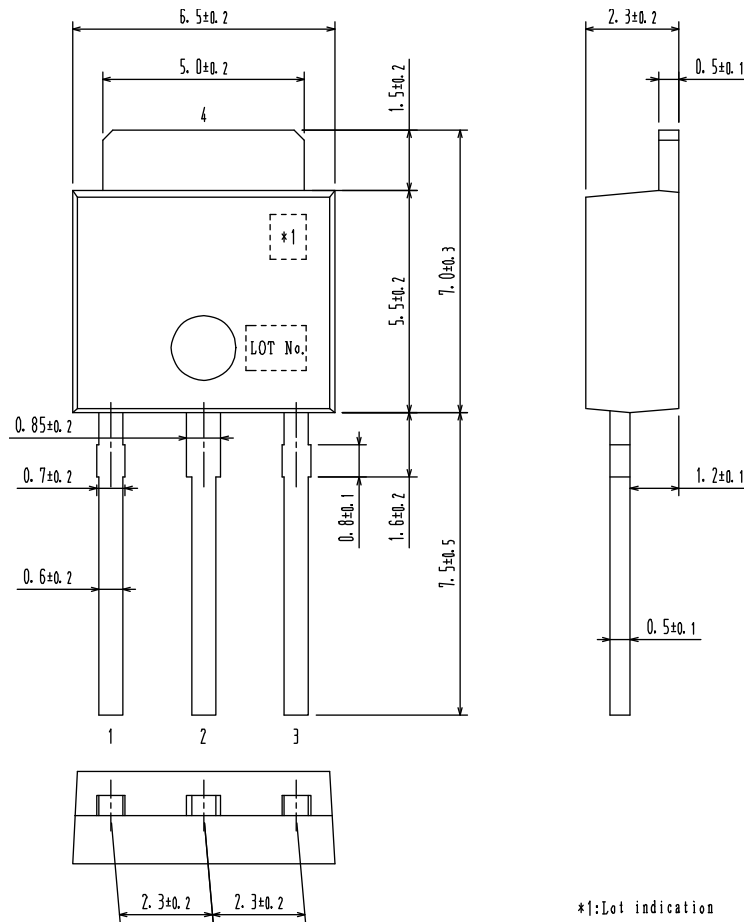


1:Gate

2:Drain

3:Source

4:Drain



*1:Lot indication

Ordering & Package Information

Device	Package	Shipping	Note
SFT1443-H	IPAK(TP) SC-64,TO-251	500pcs. / bag	Pb-Free and Halogen Free
SFT1443-W			
SFT1443-TL-H	DPAK(TP-FA) SC-63,TO-252	700pcs. / reel	
SFT1443-TL-W			

Note on usage : Since the SFT1443 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

ON Semiconductor and the ON logo are registered trademarks of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries. SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9